NSN 5961-01-353-5529

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-5529 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.140 inches and 0.185 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** Between 0.085 inches and 0.140 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Quality assurance level tx **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 77.9 breakdown voltage, dc and 86.1 breakdown voltage, dc **Current Rating Per Characteristic:** 15.00 milliamperes collector current, dc horsepower metric **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/516 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**